

1. General description

Planar passivated four quadrant triac in a SOT186A (TO-220F) "full pack" plastic package intended for use in applications requiring high bidirectional transient and blocking voltage capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

2. Features and benefits

- High blocking voltage capability
- Isolated package
- Less sensitive gate for improved noise immunity
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

3. Applications

- General purpose motor control
- General purpose switching

4. Quick reference data

| Table 1. Q | uick reference data | | | | | |
|---------------------|--|--|----|-------|-----|------|
| Symbol | Parameter | Conditions | Mi | n Typ | Max | Unit |
| V _{DRM} | repetitive peak off- state voltage | | - | - | 800 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 20 ms; <u>Fig. 4; Fig. 5</u> | - | - | 95 | A |
| Tj | junction temperature | | - | - | 125 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 56$ °C; Fig. 1; Fig. 2; Fig. 3 | - | - | 12 | A |
| Static chara | cteristics | · · · · · · · · · · · · · · · · · · · | | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 25 | mA |
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$ | - | 8 | 25 | mA |
| | | | | | | |





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| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|--|--|-----|-----|-----|------|
| | | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{7}$ | | - | 10 | 25 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | | - | 22 | 70 | mA |
| Dynamic chara | Dynamic characteristics | | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | | 50 | 250 | - | V/µs |

5. Pinning information

| Table 2. | Pinning | information | | |
|----------|---------|-------------------------|---|----------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | T1 | main terminal 1 | mb | T2 |
| 2 | T2 | main terminal 2 | | Sym051 |
| 3 | G | gate | | · · |
| mb | n.c. | mounting base; isolated | () (| |

6. Ordering information

| Table 3. Ordering in | formation | | | | | |
|----------------------|-----------|---|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BT138X-800F | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3-lead TO-220 "full pack" | SOT186A | | | |

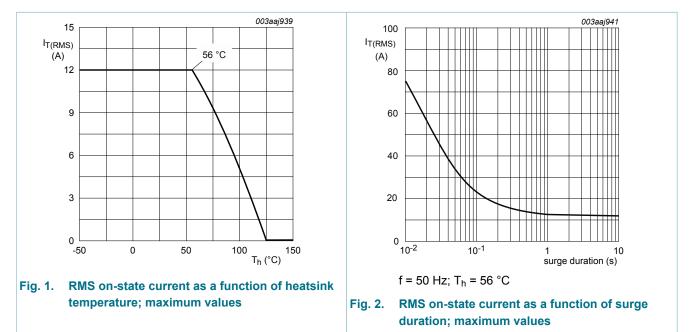
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7. Limiting values

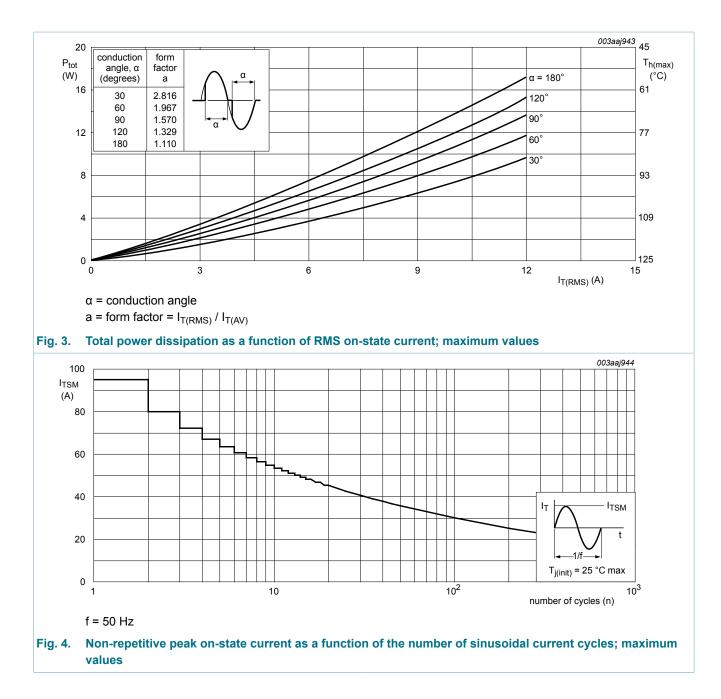
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|--------------------------------------|---|-----|-----|------------------|
| V _{DRM} | repetitive peak off-state voltage | | - | 800 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_h \le 56$ °C; Fig. 1; Fig. 2; Fig. 3 | - | 12 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; Fig. 4; Fig. 5$ | - | 95 | A |
| | | full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$ | - | 105 | A |
| l ² t | I ² t for fusing | t_p = 10 ms; sine-wave pulse | - | 45 | A ² s |
| dl _T /dt | rate of rise of on-state current | I _G = 50 mA; T2+ G+ | - | 50 | A/µs |
| | | I _G = 50 mA; T2+ G- | - | 50 | A/µs |
| | | I _G = 140 mA; T2- G+ | - | 10 | A/µs |
| | | I _G = 50 mA; T2- G- | - | 50 | A/µs |
| I _{GM} | peak gate current | | - | 2 | А |
| P _{GM} | peak gate power | | - | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | 0.5 | W |
| T _{stg} | storage temperature | | -40 | 150 | °C |
| Tj | junction temperature | | - | 125 | °C |

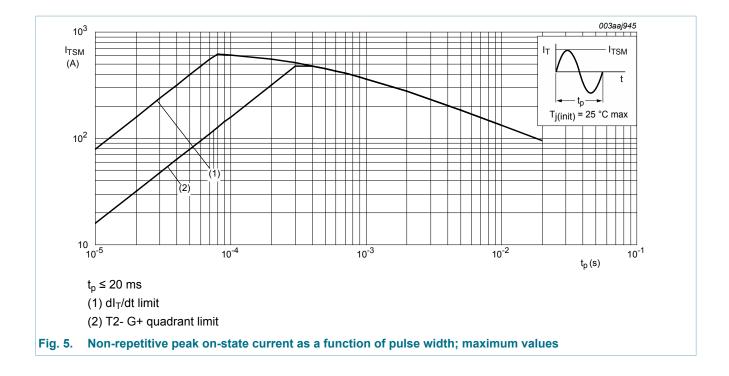


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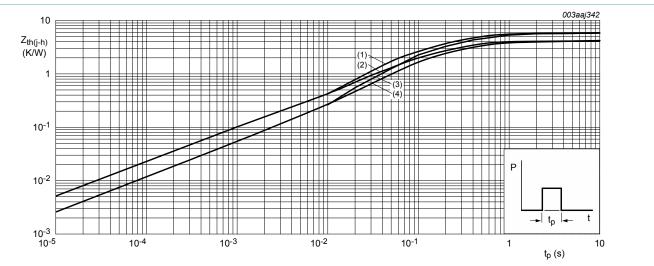
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8. Thermal characteristics

| Table 5. Thermal characteristics | | | | | | | | |
|----------------------------------|---|---|--|-----|-----|-----|------|--|
| Symbol | Parameter | Conditions | | Min | Тур | Мах | Unit | |
| from jur | thermal resistance from junction to | full or half cycle; with heatsink compound; Fig. 6 | | - | - | 4 | K/W | |
| | heatsink | full or half cycle; without heatsink compound; Fig. 6 | | - | - | 5.5 | K/W | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | | - | 55 | - | K/W | |



(1) Unidirectional (half cycle) without heatsink compound

(2) Unidirectional (half cycle) with heatsink compound

(3) Bidirectional (full cycle) without heatsink compound

(4) Bidirectional (full cycle) with heatsink compound

Fig. 6. Transient thermal impedance from junction to heatsink as a function of pulse duration

9. Isolation characteristics

| Table 6. Iso | ation characteristics | | | | | |
|------------------------|-----------------------|---|-----|-----|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz \leq f \leq 60 Hz; RH \leq 65 %; T _h = 25 °C | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from main terminal 2 to external heatsink; f = 1 MHz; T _h = 25 °C | - | 10 | - | pF |

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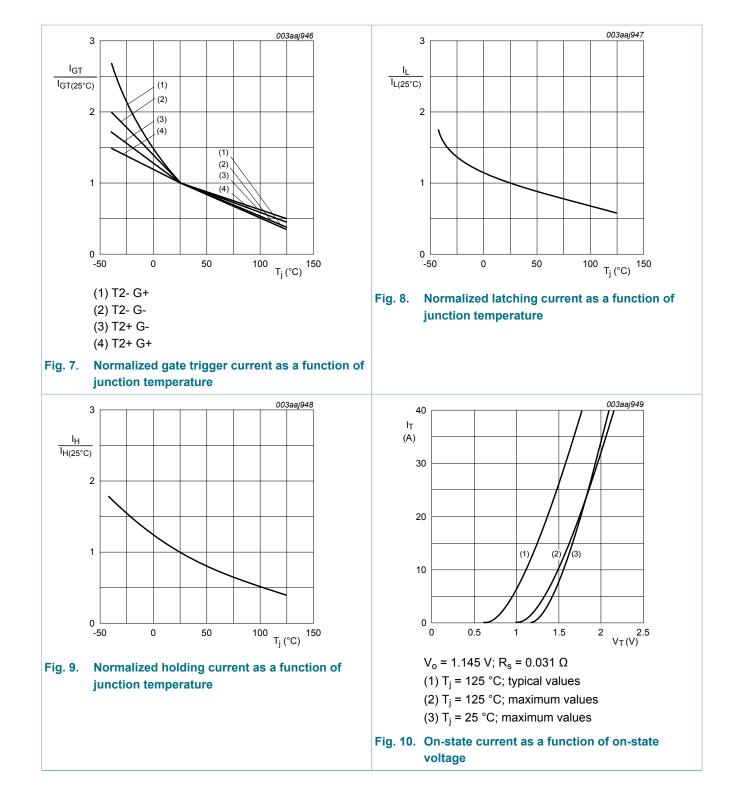
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10. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------------------------|-----------------------------------|--|------|-----|------|------|
| Static chara | acteristics | | | | | _ |
| I _{GT} gate trigger current | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | - | 5 | 25 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u> | - | 8 | 25 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u> | - | 10 | 25 | mA |
| | | V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u> | - | 22 | 70 | mA |
| lL | latching current | V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u> | - | 7 | 40 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u> | - | 20 | 60 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u> | - | 8 | 40 | mA |
| | | V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u> | - | 10 | 60 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | 6 | 30 | mA |
| V _T | on-state voltage | I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.4 | 1.65 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 800 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic cł | naracteristics | · | I | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit | 50 | 250 | - | V/µs |
| t _{gt} | gate-controlled turn-on time | I_{TM} = 16 A; V_D = 800 V; I_G = 0.1 A; dI_G/dt = 5 A/µs | - | 2 | - | μs |
| | | | | | | |

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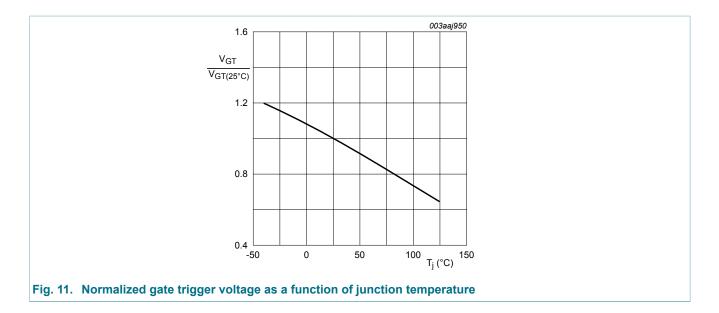


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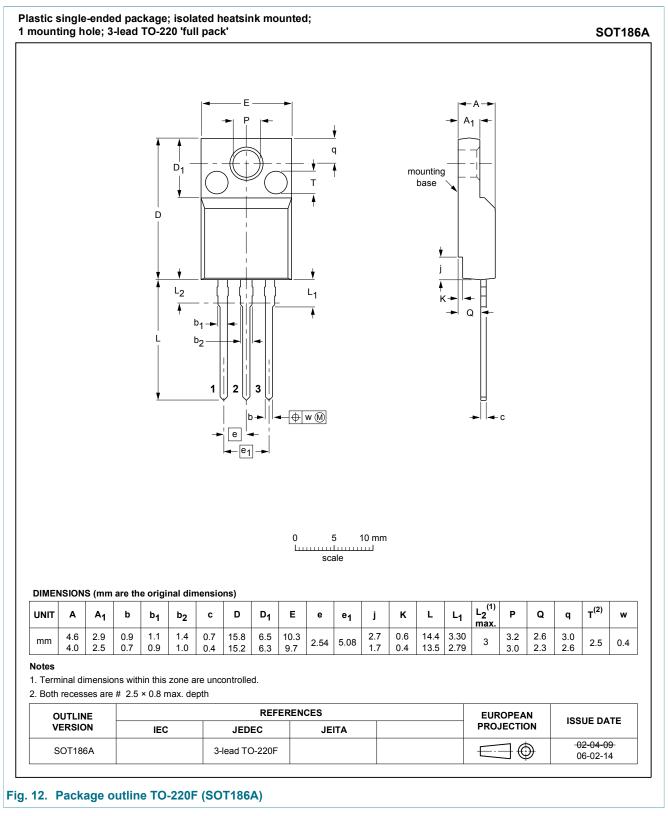


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11. Package outline



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12. Legal information

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|--------------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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